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### **Understanding Embedded - FPGAs (Field Programmable Gate Array)**

Embedded - FPGAs, or Field Programmable Gate Arrays, are advanced integrated circuits that offer unparalleled flexibility and performance for digital systems. Unlike traditional fixed-function logic devices, FPGAs can be programmed and reprogrammed to execute a wide array of logical operations, enabling customized functionality tailored to specific applications. This reprogrammability allows developers to iterate designs quickly and implement complex functions without the need for custom hardware.

### **Applications of Embedded - FPGAs**

The versatility of Embedded - FPGAs makes them indispensable in numerous fields. In telecommunications,

#### **Details**

Product Status	Active
Number of LABs/CLBs	-
Number of Logic Elements/Cells	-
Total RAM Bits	276480
Number of I/O	444
Number of Gates	1500000
Voltage - Supply	1.425V ~ 1.575V
Mounting Type	Surface Mount
Operating Temperature	-40°C ~ 100°C (TJ)
Package / Case	676-BGA
Supplier Device Package	676-FBGA (27x27)
Purchase URL	<a href="https://www.e-xfl.com/product-detail/microchip-technology/a3pe1500-1fg676i">https://www.e-xfl.com/product-detail/microchip-technology/a3pe1500-1fg676i</a>

Specify I/O States During Programming				
	Port Name	Macro Cell	Pin Number	I/O State (Output Only)
	BIST	ADLIB:INBUF	T2	1
	BYPASS_IO	ADLIB:INBUF	K1	1
	CLK	ADLIB:INBUF	B1	1
	ENOUT	ADLIB:INBUF	J16	1
	LED	ADLIB:OUTBUF	M3	0
	MONITOR[0]	ADLIB:OUTBUF	B5	0
	MONITOR[1]	ADLIB:OUTBUF	C7	Z
	MONITOR[2]	ADLIB:OUTBUF	D9	Z
	MONITOR[3]	ADLIB:OUTBUF	D7	Z
	MONITOR[4]	ADLIB:OUTBUF	A11	Z
	OEa	ADLIB:INBUF	E4	Z
	OEb	ADLIB:INBUF	F1	Z
	OSC_EN	ADLIB:INBUF	K3	Z
	PAD[10]	ADLIB:BIBUF_LVCMOS33U	M8	Z
	PAD[11]	ADLIB:BIBUF_LVCMOS33D	R7	Z
	PAD[12]	ADLIB:BIBUF_LVCMOS33U	D11	Z
	PAD[13]	ADLIB:BIBUF_LVCMOS33D	C12	Z
	PAD[14]	ADLIB:BIBUF_LVCMOS33U	R6	Z
				-

**Help**      **OK**      **Cancel**

**Figure 1-3 • I/O States During Programming Window**

6. Click OK to return to the FlashPoint – Programming File Generator window.
- I/O States during programming are saved to the ADB and resulting programming files after completing programming file generation.

## Overview of I/O Performance

### Summary of I/O DC Input and Output Levels – Default I/O Software Settings

**Table 2-13 • Summary of Maximum and Minimum DC Input and Output Levels  
Applicable to Commercial and Industrial Conditions**

I/O Standard	Drive Strength	Equivalent Software Default Drive Strength Option <sup>1</sup>	Slew Rate	VIL		VIH		VOL	VOH	IOL <sup>3</sup>	IOH <sup>3</sup>
				Min. V	Max. V	Min. V	Max. V				
3.3 V LVTTL / 3.3 V LVC MOS	12 mA	12 mA	High	-0.3	0.8	2	3.6	0.4	2.4	12	12
3.3 V LVC MOS Wide Range	100 µA	12 mA	High	-0.3	0.8	2	3.6	0.2	VCCI - 0.2	0.1	0.1
2.5 V LVC MOS	12 mA	12 mA	High	-0.3	0.7	1.7	3.6	0.7	1.7	12	12
1.8 V LVC MOS	12 mA	12 mA	High	-0.3	0.35 * VCCI	0.65 * VCCI	3.6	0.45	VCCI - 0.45	12	12
1.5 V LVC MOS	12 mA	12 mA	High	-0.3	0.30 * VCCI	0.7 * VCCI	3.6	0.25 * VCCI	0.75 * VCCI	12	12
3.3 V PCI	Per PCI Specification										
3.3 V PCI-X	Per PCI-X Specification										
3.3 V GTL	20 mA <sup>2</sup>	20 mA <sup>2</sup>	High	-0.3	VREF - 0.05	VREF + 0.05	3.6	0.4	-	20	20
2.5 V GTL	20 mA <sup>2</sup>	20 mA <sup>2</sup>	High	-0.3	VREF - 0.05	VREF + 0.05	3.6	0.4	-	20	20
3.3 V GTL+	35 mA	35 mA	High	-0.3	VREF - 0.1	VREF + 0.1	3.6	0.6	-	35	35
2.5 V GTL+	33 mA	33 mA	High	-0.3	VREF - 0.1	VREF + 0.1	3.6	0.6	-	33	33
HSTL (I)	8 mA	8 mA	High	-0.3	VREF - 0.1	VREF + 0.1	3.6	0.4	VCCI - 0.4	8	8
HSTL (II)	15 mA <sup>2</sup>	15 mA <sup>2</sup>	High	-0.3	VREF - 0.1	VREF + 0.1	3.6	0.4	VCCI - 0.4	15	15
SSTL2 (I)	15 mA	15 mA	High	-0.3	VREF - 0.2	VREF + 0.2	3.6	0.54	VCCI - 0.62	15	15
SSTL2 (II)	18 mA	18 mA	High	-0.3	VREF - 0.2	VREF + 0.2	3.6	0.35	VCCI - 0.43	18	18
SSTL3 (I)	14 mA	14 mA	High	-0.3	VREF - 0.2	VREF + 0.2	3.6	0.7	VCCI - 1.1	14	14
SSTL3 (II)	21 mA	21 mA	High	-0.3	VREF - 0.2	VREF + 0.2	3.6	0.5	VCCI - 0.9	21	21

**Notes:**

1. The minimum drive strength for any LVC MOS 3.3 V software configuration when run in wide range is  $\pm 100 \mu A$ . Drive strength displayed in the software is supported for normal range only. For a detailed I/V curve, refer to the IBIS models.
2. Output drive strength is below JEDEC specification.
3. Currents are measured at 85°C junction temperature.
4. Output Slew Rates can be extracted from IBIS Models, located at [http://www.microsemi.com/index.php?option=com\\_content&id=1671&lang=en&view=article](http://www.microsemi.com/index.php?option=com_content&id=1671&lang=en&view=article).

**Table 2-21 • I/O Short Currents IOSH/IOSL**

	<b>Drive Strength</b>	<b>IOSH (mA)*</b>	<b>IOSL (mA)*</b>
3.3 V LVTTL / 3.3 V LVCMOS	2 mA	25	27
	4 mA	25	27
	6 mA	51	54
	8 mA	51	54
	12 mA	103	109
	16 mA	132	127
	24 mA	268	181
3.3 V LVCMOS Wide Range	100 µA	Same as regular 3.3 V LVCMOS	Same as regular 3.3 V LVCMOS
2.5 V LVCMOS	4 mA	16	18
	8 mA	32	37
	12 mA	65	74
	16 mA	83	87
	24 mA	169	124
1.8 V LVCMOS	2 mA	9	11
	4 mA	17	22
	6 mA	35	44
	8 mA	45	51
	12 mA	91	74
	16 mA	91	74
1.5 V LVCMOS	2 mA	13	16
	4 mA	25	33
	6 mA	32	39
	8 mA	66	55
	12 mA	66	55

**Notes:**

1.  $T_J = 100^\circ\text{C}$
2. Applicable to 3.3 V LVCMOS Wide Range. IOSL/IOSH dependent on the I/O buffer drive strength selected for wide range applications. All LVCMOS 3.3 V software macros support LVCMOS 3.3 V wide range as specified in the JESD8b specification.

The length of time an I/O can withstand IOSH/IOSL events depends on the junction temperature. The reliability data below is based on a 3.3 V, 36 mA I/O setting, which is the worst case for this type of analysis.

For example, at  $100^\circ\text{C}$ , the short current condition would have to be sustained for more than six months to cause a reliability concern. The I/O design does not contain any short circuit protection, but such protection would only be needed in extremely prolonged stress conditions.

**Table 2-22 • Duration of Short Circuit Event Before Failure**

<b>Temperature</b>	<b>Time before Failure</b>
-40°C	> 20 years
0°C	> 20 years
25°C	> 20 years
70°C	5 years

### Timing Characteristics

**Table 2-31 • 3.3 V LVC MOS Wide Range High Slew**Commercial-Case Conditions:  $T_J = 70^\circ\text{C}$ , Worst-Case VCC = 1.425 V, Worst-Case VCCI = 2.7 V

Drive Strength	Equivalent Software Default Drive Strength Option <sup>1</sup>	Speed Grade	$t_{DOUT}$	$t_{DP}$	$t_{DIN}$	$t_{PY}$	$t_{PYS}$	$t_{EOUT}$	$t_{ZL}$	$t_{ZH}$	$t_{LZ}$	$t_{HZ}$	$t_{ZLS}$	$t_{ZHS}$	Units
100 $\mu\text{A}$	4 mA	Std.	0.66	12.19	0.04	1.83	2.38	0.43	12.19	10.17	4.16	4.00	15.58	13.57	ns
		-1	0.56	10.37	0.04	1.55	2.02	0.36	10.37	8.66	3.54	3.41	13.26	11.54	ns
		-2	0.49	9.10	0.03	1.36	1.78	0.32	9.10	7.60	3.11	2.99	11.64	10.13	ns
100 $\mu\text{A}$	8 mA	Std.	0.66	7.85	0.04	1.83	2.38	0.43	7.85	6.29	4.71	4.97	11.24	9.68	ns
		-1	0.56	6.68	0.04	1.55	2.02	0.36	6.68	5.35	4.01	4.22	9.57	8.24	ns
		-2	0.49	5.86	0.03	1.36	1.78	0.32	5.86	4.70	3.52	3.71	8.40	7.23	ns
100 $\mu\text{A}$	12 mA	Std.	0.66	5.67	0.04	1.83	2.38	0.43	5.67	4.36	5.06	5.59	9.07	7.75	ns
		-1	0.56	4.82	0.04	1.55	2.02	0.36	4.82	3.71	4.31	4.75	7.71	6.59	ns
		-2	0.49	4.24	0.03	1.36	1.78	0.32	4.24	3.25	3.78	4.17	6.77	5.79	ns
100 $\mu\text{A}$	16 mA	Std.	0.66	5.35	0.04	1.83	2.38	0.43	5.35	3.96	5.15	5.76	8.75	7.35	ns
		-1	0.56	4.55	0.04	1.55	2.02	0.36	4.55	3.36	4.38	4.90	7.44	6.25	ns
		-2	0.49	4.00	0.03	1.36	1.78	0.32	4.00	2.95	3.85	4.30	6.53	5.49	ns
100 $\mu\text{A}$	24 mA	Std.	0.66	4.96	0.04	1.83	2.38	0.43	4.96	3.27	5.23	6.38	8.35	6.67	ns
		-1	0.56	4.22	0.04	1.55	2.02	0.36	4.22	2.78	4.45	5.43	7.11	5.67	ns
		-2	0.49	3.70	0.03	1.36	1.78	0.32	3.70	2.44	3.91	4.76	6.24	4.98	ns

**Notes:**

1. The minimum drive strength for any LVC MOS 3.3 V software configuration when run in wide range is  $\pm 100 \mu\text{A}$ . Drive strength displayed in the software is supported for normal range only. For a detailed I/V curve, refer to the IBIS models.
2. Software default selection highlighted in gray.
3. For specific junction temperature and voltage supply levels, refer to Table 2-6 on page 2-5 for derating values.

### Timing Characteristics

**Table 2-35 • 2.5 V LVC MOS High Slew**

Commercial-Case Conditions:  $T_J = 70^\circ\text{C}$ , Worst-Case VCC = 1.425 V, Worst-Case VCCI = 2.3 V

Drive Strength	Speed Grade	$t_{DOUT}$	$t_{DP}$	$t_{DIN}$	$t_{PY}$	$t_{PYS}$	$t_{EOUT}$	$t_{ZL}$	$t_{ZH}$	$t_{LZ}$	$t_{HZ}$	$t_{ZLS}$	$t_{ZHS}$	Units
4 mA	Std.	0.66	8.82	0.04	1.51	1.66	0.43	8.13	8.82	2.72	2.29	10.37	11.05	ns
	-1	0.56	7.50	0.04	1.29	1.41	0.36	6.92	7.50	2.31	1.95	8.82	9.40	ns
	-2	0.49	6.58	0.03	1.13	1.24	0.32	6.07	6.58	2.03	1.71	7.74	8.25	ns
8 mA	Std.	0.66	5.27	0.04	1.51	1.66	0.43	5.27	5.27	3.10	3.03	7.50	7.51	ns
	-1	0.56	4.48	0.04	1.29	1.41	0.36	4.48	4.48	2.64	2.58	6.38	6.38	ns
	-2	0.49	3.94	0.03	1.13	1.24	0.32	3.93	3.94	2.32	2.26	5.60	5.61	ns
12 mA	Std.	0.66	3.74	0.04	1.51	1.66	0.43	3.81	3.49	3.37	3.49	6.05	5.73	ns
	-1	0.56	3.18	0.04	1.29	1.41	0.36	3.24	2.97	2.86	2.97	5.15	4.87	ns
	-2	0.49	2.80	0.03	1.13	1.24	0.32	2.85	2.61	2.51	2.61	4.52	4.28	ns
16 mA	Std.	0.66	3.53	0.04	1.51	1.66	0.43	3.59	3.12	3.42	3.62	5.83	5.35	ns
	-1	0.56	3.00	0.04	1.29	1.41	0.36	3.06	2.65	2.91	3.08	4.96	4.55	ns
	-2	0.49	2.63	0.03	1.13	1.24	0.32	2.68	2.33	2.56	2.71	4.35	4.00	ns
24 mA	Std.	0.66	3.26	0.04	1.51	1.66	0.43	3.32	2.48	3.49	4.11	5.56	4.72	ns
	-1	0.56	2.77	0.04	1.29	1.41	0.36	2.83	2.11	2.97	3.49	4.73	4.01	ns
	-2	0.49	2.44	0.03	1.13	1.24	0.32	2.48	1.85	2.61	3.07	4.15	3.52	ns

**Notes:**

1. Software default selection highlighted in gray.
2. For specific junction temperature and voltage supply levels, refer to Table 2-6 on page 2-5 for derating values.

**Table 2-36 • 2.5 V LVC MOS Low Slew**

 Commercial-Case Conditions:  $T_J = 70^\circ\text{C}$ , Worst-Case VCC = 1.425 V, Worst-Case VCCI = 2.3 V

Drive Strength	Speed Grade	$t_{DOUT}$	$t_{DP}$	$t_{DIN}$	$t_{PY}$	$t_{PYS}$	$t_{EOUT}$	$t_{ZL}$	$t_{ZH}$	$t_{LZ}$	$t_{HZ}$	$t_{ZLS}$	$t_{ZHS}$	Units
4 mA	Std.	0.66	12.00	0.04	1.51	1.66	0.43	12.23	11.61	2.72	2.20	14.46	13.85	ns
	-1	0.56	10.21	0.04	1.29	1.41	0.36	10.40	9.88	2.31	1.87	12.30	11.78	ns
	-2	0.49	8.96	0.03	1.13	1.24	0.32	9.13	8.67	2.03	1.64	10.80	10.34	ns
8 mA	Std.	0.66	8.73	0.04	1.51	1.66	0.43	8.89	8.01	3.10	2.93	11.13	10.25	ns
	-1	0.56	7.43	0.04	1.29	1.41	0.36	7.57	6.82	2.64	2.49	9.47	8.72	ns
	-2	0.49	6.52	0.03	1.13	1.24	0.32	6.64	5.98	2.32	2.19	8.31	7.65	ns
12 mA	Std.	0.66	6.77	0.04	1.51	1.66	0.43	6.90	6.11	3.37	3.39	9.14	8.34	ns
	-1	0.56	5.76	0.04	1.29	1.41	0.36	5.87	5.20	2.86	2.89	7.77	7.10	ns
	-2	0.49	5.06	0.03	1.13	1.24	0.32	5.15	4.56	2.51	2.53	6.82	6.23	ns
16 mA	Std.	0.66	6.31	0.04	1.51	1.66	0.43	6.42	5.73	3.42	3.52	8.66	7.96	ns
	-1	0.56	5.37	0.04	1.29	1.41	0.36	5.46	4.87	2.91	3.00	7.37	6.77	ns
	-2	0.49	4.71	0.03	1.13	1.24	0.32	4.80	4.28	2.56	2.63	6.47	5.95	ns
24 mA	Std.	0.66	5.93	0.04	1.51	1.66	0.43	6.04	5.70	3.49	4.00	8.28	7.94	ns
	-1	0.56	5.05	0.04	1.29	1.41	0.36	5.14	4.85	2.97	3.40	7.04	6.75	ns
	-2	0.49	4.43	0.03	1.13	1.24	0.32	4.51	4.26	2.61	2.99	6.18	5.93	ns

*Note:* For specific junction temperature and voltage supply levels, refer to [Table 2-6 on page 2-5](#) for derating values.

**Table 2-40 • 1.8 V LVC MOS Low Slew**Commercial-Case Conditions:  $T_J = 70^\circ\text{C}$ , Worst-Case VCC = 1.425 V, Worst-Case VCCI = 1.7 V

Drive Strength	Speed Grade	$t_{DOUT}$	$t_{DP}$	$t_{DIN}$	$t_{PY}$	$t_{PYS}$	$t_{EOUT}$	$t_{ZL}$	$t_{ZH}$	$t_{LZ}$	$t_{HZ}$	$t_{ZLS}$	$t_{ZHS}$	Units
2 mA	Std.	0.66	15.84	0.04	1.45	1.91	0.43	15.65	15.84	2.78	1.58	17.89	18.07	ns
	-1	0.56	13.47	0.04	1.23	1.62	0.36	13.31	13.47	2.37	1.35	15.22	15.37	ns
	-2	0.49	11.83	0.03	1.08	1.42	0.32	11.69	11.83	2.08	1.18	13.36	13.50	ns
4 mA	Std.	0.66	11.39	0.04	1.45	1.91	0.43	11.60	10.76	3.26	2.77	13.84	12.99	ns
	-1	0.56	9.69	0.04	1.23	1.62	0.36	9.87	9.15	2.77	2.36	11.77	11.05	ns
	-2	0.49	8.51	0.03	1.08	1.42	0.32	8.66	8.03	2.43	2.07	10.33	9.70	ns
6 mA	Std.	0.66	8.97	0.04	1.45	1.91	0.43	9.14	8.10	3.57	3.36	11.37	10.33	ns
	-1	0.56	7.63	0.04	1.23	1.62	0.36	7.77	6.89	3.04	2.86	9.67	8.79	ns
	-2	0.49	6.70	0.03	1.08	1.42	0.32	6.82	6.05	2.66	2.51	8.49	7.72	ns
8 mA	Std.	0.66	8.35	0.04	1.45	1.91	0.43	8.50	7.59	3.64	3.52	10.74	9.82	ns
	-1	0.56	7.10	0.04	1.23	1.62	0.36	7.23	6.45	3.10	3.00	9.14	8.35	ns
	-2	0.49	6.24	0.03	1.08	1.42	0.32	6.35	5.66	2.72	2.63	8.02	7.33	ns
12 mA	Std.	0.66	7.94	0.04	1.45	1.91	0.43	8.09	7.56	3.74	4.11	10.32	9.80	ns
	-1	0.56	6.75	0.04	1.23	1.62	0.36	6.88	6.43	3.18	3.49	8.78	8.33	ns
	-2	0.49	5.93	0.03	1.08	1.42	0.32	6.04	5.65	2.79	3.07	7.71	7.32	ns
16 mA	Std.	0.66	7.94	0.04	1.45	1.91	0.43	8.09	7.56	3.74	4.11	10.32	9.80	ns
	-1	0.56	6.75	0.04	1.23	1.62	0.36	6.88	6.43	3.18	3.49	8.78	8.33	ns
	-2	0.49	5.93	0.03	1.08	1.42	0.32	6.04	5.65	2.79	3.07	7.71	7.32	ns

*Note:* For specific junction temperature and voltage supply levels, refer to [Table 2-6 on page 2-5](#) for derating values.

### HSTL Class I

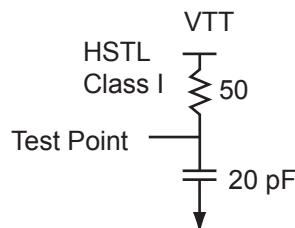
High-Speed Transceiver Logic is a general-purpose high-speed 1.5 V bus standard (EIA/JESD8-6). ProASIC3E devices support Class I. This provides a differential amplifier input buffer and a push-pull output buffer.

**Table 2-60 • Minimum and Maximum DC Input and Output Levels**

HSTL Class I	VIL		VIH		VOL	VOH	IOL	IOH	IOSL	IOSH	IIL	IIH
Drive Strength	Min. V	Max. V	Min. V	Max. V	Max. V	Min. V	mA	mA	Max. mA <sup>1</sup>	Max. mA <sup>1</sup>	μA <sup>2</sup>	μA <sup>2</sup>
8 mA	-0.3	VREF - 0.1	VREF + 0.1	3.6	0.4	VCCI - 0.4	8	8	39	32	10	10

*Notes:*

1. Currents are measured at high temperature (100°C junction temperature) and maximum voltage.
2. Currents are measured at 85°C junction temperature.



**Figure 2-16 • AC Loading**

**Table 2-61 • AC Waveforms, Measuring Points, and Capacitive Loads**

Input Low (V)	Input High (V)	Measuring Point* (V)	VREF (typ.) (V)	VTT (typ.) (V)	C <sub>LOAD</sub> (pF)
VREF - 0.1	VREF + 0.1	0.75	0.75	0.75	20

*Note:* \*Measuring point = V<sub>trip</sub>. See [Table 2-15 on page 2-18](#) for a complete table of trip points.

### Timing Characteristics

**Table 2-62 • HSTL Class I**

Commercial-Case Conditions: T<sub>J</sub> = 70°C, Worst-Case VCC = 1.425 V,  
Worst-Case VCCI = .4 V, VREF = 0.75 V

Speed Grade	t <sub>DOUT</sub>	t <sub>DP</sub>	t <sub>DIN</sub>	t <sub>PY</sub>	t <sub>EOUT</sub>	t <sub>ZL</sub>	t <sub>ZH</sub>	t <sub>LZ</sub>	t <sub>HZ</sub>	t <sub>ZLS</sub>	t <sub>ZHS</sub>	Units
Std.	0.66	3.18	0.04	2.12	0.43	3.24	3.14			5.47	5.38	ns
-1	0.56	2.70	0.04	1.81	0.36	2.75	2.67			4.66	4.58	ns
-2	0.49	2.37	0.03	1.59	0.32	2.42	2.35			4.09	4.02	ns

*Note:* For specific junction temperature and voltage supply levels, refer to [Table 2-6 on page 2-5](#) for derating values.

## HSTL Class II

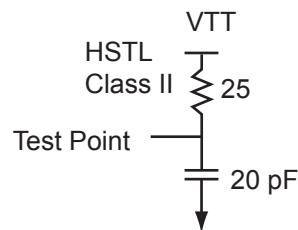
High-Speed Transceiver Logic is a general-purpose high-speed 1.5 V bus standard (EIA/JESD8-6). ProASIC3E devices support Class II. This provides a differential amplifier input buffer and a push-pull output buffer.

**Table 2-63 • Minimum and Maximum DC Input and Output Levels**

HSTL Class II	VIL		VIH		VOL	VOH	IOL	IOH	IOSL	IOSH	IIL	IIH
Drive Strength	Min. V	Max. V	Min. V	Max. V	Max., V	Min. V	mA	mA	Max. mA <sup>1</sup>	Max. mA <sup>1</sup>	μA <sup>2</sup>	μA <sup>2</sup>
15 mA <sup>3</sup>	-0.3	VREF - 0.1	VREF + 0.1	3.6	0.4	VCCI - 0.4	15	15	55	66	10	10

*Notes:*

1. Currents are measured at high temperature (100°C junction temperature) and maximum voltage.
2. Currents are measured at 85°C junction temperature.
3. Output drive strength is below JEDEC specification.



**Figure 2-17 • AC Loading**

**Table 2-64 • AC Waveforms, Measuring Points, and Capacitive Loads**

Input Low (V)	Input High (V)	Measuring Point* (V)	VREF (typ.) (V)	VTT (typ.) (V)	C <sub>LOAD</sub> (pF)
VREF - 0.1	VREF + 0.1	0.75	0.75	0.75	20

*Note:* \*Measuring point = Vtrip. See [Table 2-15 on page 2-18](#) for a complete table of trip points.

## Timing Characteristics

**Table 2-65 • HSTL Class II**

Commercial-Case Conditions:  $T_J = 70^\circ\text{C}$ , Worst-Case VCC = 1.425 V,  
Worst-Case VCCI = 1.4 V, VREF = 0.75 V

Speed Grade	t <sub>DOUT</sub>	t <sub>DP</sub>	t <sub>DIN</sub>	t <sub>PY</sub>	t <sub>EOUT</sub>	t <sub>ZL</sub>	t <sub>ZH</sub>	t <sub>LZ</sub>	t <sub>HZ</sub>	t <sub>ZLS</sub>	t <sub>ZHS</sub>	Units
Std.	0.66	3.02	0.04	2.12	0.43	3.08	2.71			5.32	4.95	ns
-1	0.56	2.57	0.04	1.81	0.36	2.62	2.31			4.52	4.21	ns
-2	0.49	2.26	0.03	1.59	0.32	2.30	2.03			3.97	3.70	ns

*Note:* For specific junction temperature and voltage supply levels, refer to [Table 2-6 on page 2-5](#) for derating values.

### Timing Characteristics

**Table 2-80 • LVDS**

Commercial-Case Conditions:  $T_J = 70^\circ\text{C}$ , Worst-Case  $V_{CC} = 1.425 \text{ V}$ , Worst-Case  $V_{CCI} = 2.3 \text{ V}$

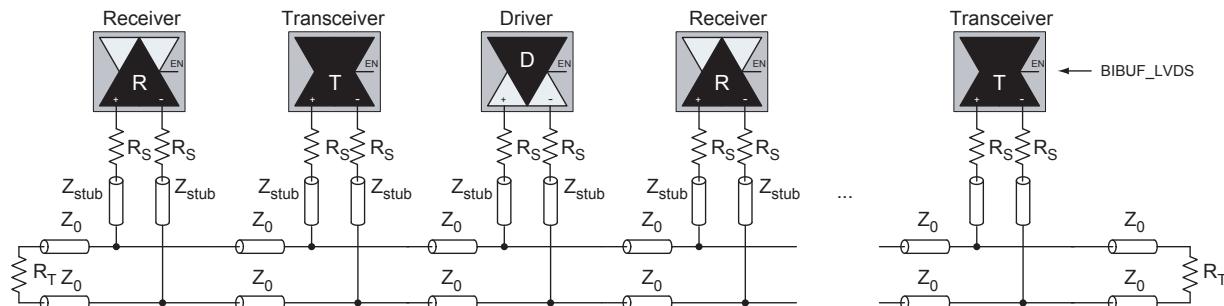
Speed Grade	$t_{DOUT}$	$t_{DP}$	$t_{DIN}$	$t_{PY}$	Units
Std.	0.66	1.87	0.04	1.82	ns
-1	0.56	1.59	0.04	1.55	ns
-2	0.49	1.40	0.03	1.36	ns

**Note:** For specific junction temperature and voltage supply levels, refer to [Table 2-6 on page 2-5](#) for derating values.

### B-LVDS/M-LVDS

Bus LVDS (B-LVDS) and Multipoint LVDS (M-LVDS) specifications extend the existing LVDS standard to high-performance multipoint bus applications. Multidrop and multipoint bus configurations may contain any combination of drivers, receivers, and transceivers. Microsemi LVDS drivers provide the higher drive current required by B-LVDS and M-LVDS to accommodate the loading. The drivers require series terminations for better signal quality and to control voltage swing. Termination is also required at both ends of the bus since the driver can be located anywhere on the bus. These configurations can be implemented using the TRIBUF\_LVDS and BIBUF\_LVDS macros along with appropriate terminations. Multipoint designs using Microsemi LVDS macros can achieve up to 200 MHz with a maximum of 20 loads. A sample application is given in [Figure 2-23](#). The input and output buffer delays are available in the LVDS section in [Table 2-80](#).

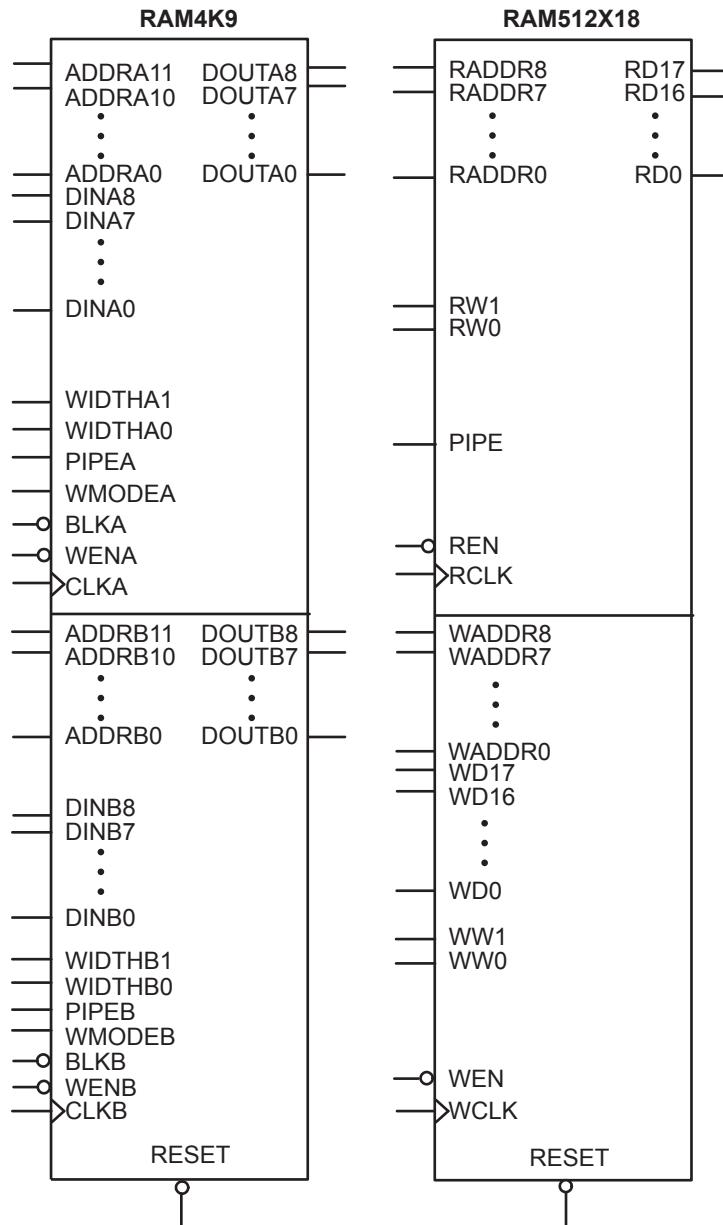
Example: For a bus consisting of 20 equidistant loads, the following terminations provide the required differential voltage, in worst-case Industrial operating conditions, at the farthest receiver:  $R_S = 60 \Omega$  and  $R_T = 70 \Omega$ , given  $Z_0 = 50 \Omega$  (2") and  $Z_{\text{stub}} = 50 \Omega$  (~1.5").



**Figure 2-23 • B-LVDS/M-LVDS Multipoint Application Using LVDS I/O Buffers**

## Embedded SRAM and FIFO Characteristics

### SRAM



**Figure 2-40 • RAM Models**

**Table 2-100 • RAM512X18**Commercial-Case Conditions:  $T_J = 70^\circ\text{C}$ , Worst-Case VCC = 1.425 V

Parameter	Description	-2	-1	Std.	Units
$t_{AS}$	Address setup time	0.25	0.28	0.33	ns
$t_{AH}$	Address hold time	0.00	0.00	0.00	ns
$t_{ENS}$	REN, WEN setup time	0.18	0.20	0.24	ns
$t_{ENH}$	REN, WEN hold time	0.06	0.07	0.08	ns
$t_{DS}$	Input data (WD) setup time	0.18	0.21	0.25	ns
$t_{DH}$	Input data (WD) hold time	0.00	0.00	0.00	ns
$t_{CKQ1}$	Clock High to new data valid on RD (output retained)	2.16	2.46	2.89	ns
$t_{CKQ2}$	Clock High to new data valid on RD (pipelined)	0.90	1.02	1.20	ns
$t_{C2CRWH}^1$	Address collision clk-to-clk delay for reliable read access after write on same address—Applicable to Opening Edge	0.50	0.43	0.38	ns
$t_{C2CWRH}^1$	Address collision clk-to-clk delay for reliable write access after read on same address— Applicable to Opening Edge	0.59	0.50	0.44	ns
$t_{RSTBQ}$	RESET Low to data out Low on RD (flow-through)	0.92	1.05	1.23	ns
	RESET Low to data out Low on RD (pipelined)	0.92	1.05	1.23	ns
$t_{REMRSTB}$	RESET removal	0.29	0.33	0.38	ns
$t_{RECRSTB}$	RESET recovery	1.50	1.71	2.01	ns
$t_{MPWRSTB}$	RESET minimum pulse width	0.21	0.24	0.29	ns
$t_{CYC}$	Clock cycle time	3.23	3.68	4.32	ns
$F_{MAX}$	Maximum frequency	310	272	231	MHz

**Notes:**

1. For more information, refer to the application note [Simultaneous Read-Write Operations in Dual-Port SRAM for Flash-Based cSoCs and FPGAs](#).
2. For specific junction temperature and voltage supply levels, refer to [Table 2-6](#) on page [2-5](#) for derating values.

<b>FG256</b>	
<b>Pin Number</b>	<b>A3PE600 Function</b>
G13	GCC1/IO50PPB2V1
G14	IO44NDB2V1
G15	IO44PDB2V1
G16	IO49NSB2V1
H1	GFB0/IO119NPB7V0
H2	GFA0/IO118NDB6V1
H3	GFB1/IO119PPB7V0
H4	VCOMPLF
H5	GFC0/IO120NPB7V0
H6	VCC
H7	GND
H8	GND
H9	GND
H10	GND
H11	VCC
H12	GCC0/IO50NPB2V1
H13	GCB1/IO51PPB2V1
H14	GCA0/IO52NPB3V0
H15	VCOMPLC
H16	GCB0/IO51NPB2V1
J1	GFA2/IO117PSB6V1
J2	GFA1/IO118PDB6V1
J3	VCCPLF
J4	IO116NDB6V1
J5	GFB2/IO116PDB6V1
J6	VCC
J7	GND
J8	GND
J9	GND
J10	GND
J11	VCC
J12	GCB2/IO54PPB3V0
J13	GCA1/IO52PPB3V0
J14	GCC2/IO55PPB3V0
J15	VCCPLC
J16	GCA2/IO53PSB3V0

<b>FG256</b>	
<b>Pin Number</b>	<b>A3PE600 Function</b>
K1	GFC2/IO115PSB6V1
K2	IO113PPB6V1
K3	IO112PDB6V1
K4	IO112NDB6V1
K5	VCCIB6
K6	VCC
K7	GND
K8	GND
K9	GND
K10	GND
K11	VCC
K12	VCCIB3
K13	IO54NPB3V0
K14	IO57NPB3V0
K15	IO55NPB3V0
K16	IO57PPB3V0
L1	IO113NPB6V1
L2	IO109PPB6V0
L3	IO108PDB6V0
L4	IO108NDB6V0
L5	VCCIB6
L6	GND
L7	VCC
L8	VCC
L9	VCC
L10	VCC
L11	GND
L12	VCCIB3
L13	GDB0/IO66NPB3V1
L14	IO60NDB3V1
L15	IO60PDB3V1
L16	IO61PDB3V1
M1	IO109NPB6V0
M2	IO106NDB6V0
M3	IO106PDB6V0
M4	GEC0/IO104NPB6V0

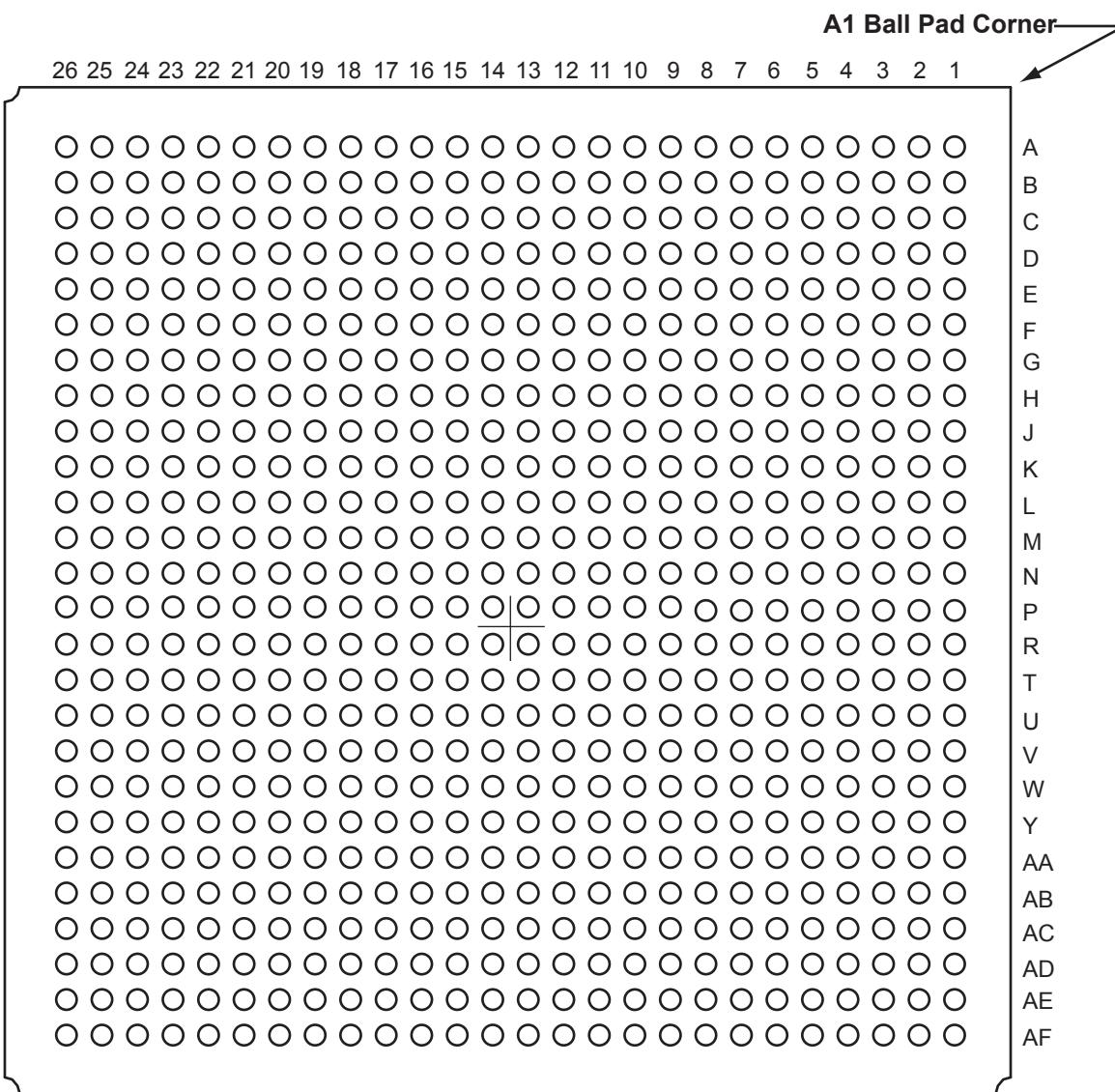
<b>FG256</b>	
<b>Pin Number</b>	<b>A3PE600 Function</b>
M5	VMV5
M6	VCCIB5
M7	VCCIB5
M8	IO84NDB5V0
M9	IO84PDB5V0
M10	VCCIB4
M11	VCCIB4
M12	VMV3
M13	VCCPLD
M14	GDB1/IO66PPB3V1
M15	GDC1/IO65PDB3V1
M16	IO61NDB3V1
N1	IO105PDB6V0
N2	IO105NDB6V0
N3	GEC1/IO104PPB6V0
N4	VCOMPLE
N5	GNDQ
N6	GEA2/IO101PPB5V2
N7	IO92NDB5V1
N8	IO90NDB5V1
N9	IO82NDB5V0
N10	IO74NDB4V1
N11	IO74PDB4V1
N12	GNDQ
N13	VCOMPLD
N14	VJTAG
N15	GDC0/IO65NDB3V1
N16	GDA1/IO67PDB3V1
P1	GEB1/IO103PDB6V0
P2	GEB0/IO103NDB6V0
P3	VMV6
P4	VCCPLE
P5	IO101NPB5V2
P6	IO95PPB5V1
P7	IO92PDB5V1
P8	IO90PDB5V1

<b>FG484</b>	
<b>Pin Number</b>	<b>A3PE3000 Function</b>
C21	IO94PPB2V1
C22	VCCIB2
D1	IO293PDB7V2
D2	IO303NDB7V3
D3	IO305NDB7V3
D4	GND
D5	GAA0/IO00NDB0V0
D6	GAA1/IO00PDB0V0
D7	GAB0/IO01NDB0V0
D8	IO20PDB0V2
D9	IO22PDB0V2
D10	IO30PDB0V3
D11	IO38NDB0V4
D12	IO52NDB1V1
D13	IO52PDB1V1
D14	IO66NDB1V3
D15	IO66PDB1V3
D16	GBB1/IO80PDB1V4
D17	GBA0/IO81NDB1V4
D18	GBA1/IO81PDB1V4
D19	GND
D20	IO88PDB2V0
D21	IO90PDB2V1
D22	IO94NPB2V1
E1	IO293NDB7V2
E2	IO299PPB7V3
E3	GND
E4	GAB2/IO308PDB7V4
E5	GAA2/IO309PDB7V4
E6	GNDQ
E7	GAB1/IO01PDB0V0
E8	IO20NDB0V2
E9	IO22NDB0V2
E10	IO30NDB0V3
E11	IO38PDB0V4
E12	IO44NDB1V0

<b>FG484</b>	
<b>Pin Number</b>	<b>A3PE3000 Function</b>
E13	IO58NDB1V2
E14	IO58PDB1V2
E15	GBC1/IO79PDB1V4
E16	GBB0/IO80NDB1V4
E17	GNDQ
E18	GBA2/IO82PDB2V0
E19	IO86NDB2V0
E20	GND
E21	IO90NDB2V1
E22	IO98PDB2V2
F1	IO299NPB7V3
F2	IO301NDB7V3
F3	IO301PDB7V3
F4	IO308NDB7V4
F5	IO309NDB7V4
F6	VMV7
F7	VCCPLA
F8	GAC0/IO02NDB0V0
F9	GAC1/IO02PDB0V0
F10	IO32NDB0V3
F11	IO32PDB0V3
F12	IO44PDB1V0
F13	IO50NDB1V1
F14	IO60PDB1V2
F15	GBC0/IO79NDB1V4
F16	VCCPLB
F17	VMV2
F18	IO82NDB2V0
F19	IO86PDB2V0
F20	IO96PDB2V1
F21	IO96NDB2V1
F22	IO98NDB2V2
G1	IO289NDB7V1
G2	IO289PDB7V1
G3	IO291PPB7V2
G4	IO295PDB7V2

<b>FG484</b>	
<b>Pin Number</b>	<b>A3PE3000 Function</b>
G5	IO297PDB7V2
G6	GAC2/IO307PDB7V4
G7	VCOMPLA
G8	GNDQ
G9	IO26NDB0V3
G10	IO26PDB0V3
G11	IO36PDB0V4
G12	IO42PDB1V0
G13	IO50PDB1V1
G14	IO60NDB1V2
G15	GNDQ
G16	VCOMPLB
G17	GBB2/IO83PDB2V0
G18	IO92PDB2V1
G19	IO92NDB2V1
G20	IO102PDB2V2
G21	IO102NDB2V2
G22	IO105NDB2V2
H1	IO286PSB7V1
H2	IO291NPB7V2
H3	VCC
H4	IO295NDB7V2
H5	IO297NDB7V2
H6	IO307NDB7V4
H7	IO287PDB7V1
H8	VMV0
H9	VCCIB0
H10	VCCIB0
H11	IO36NDB0V4
H12	IO42NDB1V0
H13	VCCIB1
H14	VCCIB1
H15	VMV1
H16	GBC2/IO84PDB2V0
H17	IO83NDB2V0
H18	IO100NDB2V2

## FG676



**Note:** This is the bottom view of the package.

### Note

For Package Manufacturing and Environmental information, visit the Resource Center at  
<http://www.microsemi.com/products/fpga-soc/solutions>.

<b>FG676</b>	
<b>Pin Number</b>	<b>A3PE1500 Function</b>
L17	GND
L18	VCC
L19	VCCIB2
L20	IO67PDB2V1
L21	IO67NDB2V1
L22	IO71PDB2V2
L23	IO71NDB2V2
L24	GNDQ
L25	IO82PDB2V3
L26	IO84NDB2V3
M1	IO198NPB7V0
M2	IO202PDB7V1
M3	IO202NDB7V1
M4	IO206NDB7V1
M5	IO206PDB7V1
M6	IO204NDB7V1
M7	IO204PDB7V1
M8	VCCIB7
M9	VCC
M10	GND
M11	GND
M12	GND
M13	GND
M14	GND
M15	GND
M16	GND
M17	GND
M18	VCC
M19	VCCIB2
M20	IO73NDB2V2
M21	IO73PDB2V2
M22	IO81PPB2V3
M23	IO77PDB2V2
M24	IO77NDB2V2
M25	IO82NDB2V3
M26	IO83PDB2V3

<b>FG676</b>	
<b>Pin Number</b>	<b>A3PE1500 Function</b>
N1	GFB0/IO191NPB7V0
N2	VCOMPLF
N3	GFB1/IO191PPB7V0
N4	IO196PDB7V0
N5	GFA0/IO190NDB6V2
N6	IO200PDB7V1
N7	IO200NDB7V1
N8	VCCIB7
N9	VCC
N10	GND
N11	GND
N12	GND
N13	GND
N14	GND
N15	GND
N16	GND
N17	GND
N18	VCC
N19	VCCIB2
N20	IO79PDB2V3
N21	IO79NDB2V3
N22	GCA2/IO88PPB3V0
N23	IO81NPB2V3
N24	GCA0/IO87NDB3V0
N25	GCB0/IO86NPB2V3
N26	IO83NDB2V3
P1	GFA2/IO189PDB6V2
P2	VCCPLF
P3	IO193PPB7V0
P4	IO196NDB7V0
P5	GFA1/IO190PDB6V2
P6	IO194PDB7V0
P7	IO194NDB7V0
P8	VCCIB6
P9	VCC
P10	GND

<b>FG676</b>	
<b>Pin Number</b>	<b>A3PE1500 Function</b>
P11	GND
P12	GND
P13	GND
P14	GND
P15	GND
P16	GND
P17	GND
P18	VCC
P19	VCCIB3
P20	GCC0/IO85NDB2V3
P21	GCC1/IO85PDB2V3
P22	GCB1/IO86PPB2V3
P23	IO88NPB3V0
P24	GCA1/IO87PDB3V0
P25	VCCPLC
P26	VCOMPLC
R1	IO189NDB6V2
R2	IO185PDB6V2
R3	IO187NPB6V2
R4	IO193NPB7V0
R5	GFC2/IO187PPB6V2
R6	GFC1/IO192PDB7V0
R7	GFC0/IO192NDB7V0
R8	VCCIB6
R9	VCC
R10	GND
R11	GND
R12	GND
R13	GND
R14	GND
R15	GND
R16	GND
R17	GND
R18	VCC
R19	VCCIB3
R20	NC

<b>FG676</b>	
<b>Pin Number</b>	<b>A3PE1500 Function</b>
R21	IO89NDB3V0
R22	GCB2/IO89PDB3V0
R23	IO90NDB3V0
R24	GCC2/IO90PDB3V0
R25	IO91PDB3V0
R26	IO91NDB3V0
T1	IO186PDB6V2
T2	IO185NDB6V2
T3	GNDQ
T4	IO180PDB6V1
T5	IO180NDB6V1
T6	IO188NDB6V2
T7	GFB2/IO188PDB6V2
T8	VCCIB6
T9	VCC
T10	GND
T11	GND
T12	GND
T13	GND
T14	GND
T15	GND
T16	GND
T17	GND
T18	VCC
T19	VCCIB3
T20	IO99PDB3V1
T21	IO99NDB3V1
T22	IO97PDB3V1
T23	IO97NDB3V1
T24	GNDQ
T25	IO93PPB3V0
T26	NC
U1	IO186NDB6V2
U2	IO184NDB6V2
U3	IO184PDB6V2
U4	IO182NDB6V1

<b>FG676</b>	
<b>Pin Number</b>	<b>A3PE1500 Function</b>
U5	IO182PDB6V1
U6	IO178PDB6V1
U7	IO178NDB6V1
U8	VCCIB6
U9	VCC
U10	GND
U11	GND
U12	GND
U13	GND
U14	GND
U15	GND
U16	GND
U17	GND
U18	VCC
U19	VCCIB3
U20	NC
U21	IO101NDB3V1
U22	IO101PDB3V1
U23	IO92NDB3V0
U24	IO92PDB3V0
U25	IO95PDB3V1
U26	IO93NPB3V0
V1	IO183PDB6V2
V2	IO183NDB6V2
V3	VMV6
V4	IO181PDB6V1
V5	IO181NDB6V1
V6	IO176PDB6V1
V7	IO176NDB6V1
V8	VCCIB6
V9	VCC
V10	VCC
V11	VCC
V12	VCC
V13	VCC
V14	VCC

<b>FG676</b>	
<b>Pin Number</b>	<b>A3PE1500 Function</b>
V15	VCC
V16	VCC
V17	VCC
V18	VCC
V19	VCCIB3
V20	IO107PDB3V2
V21	IO107NDB3V2
V22	IO103NDB3V2
V23	IO103PDB3V2
V24	VMV3
V25	IO95NDB3V1
V26	IO94PDB3V0
W1	IO179NDB6V1
W2	IO179PDB6V1
W3	IO177NDB6V1
W4	IO177PDB6V1
W5	IO172PDB6V0
W6	IO172NDB6V0
W7	VCC
W8	VCC
W9	VCCIB5
W10	VCCIB5
W11	VCCIB5
W12	VCCIB5
W13	VCCIB5
W14	VCCIB4
W15	VCCIB4
W16	VCCIB4
W17	VCCIB4
W18	VCCIB4
W19	VCC
W20	VCCIB3
W21	GDB0/IO109NDB3V2
W22	GDB1/IO109PDB3V2
W23	IO105NDB3V2
W24	IO105PDB3V2

## 5 – Datasheet Information

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### List of Changes

The following table lists critical changes that were made in each revision of the ProASIC3E datasheet.

Revision	Changes	Page
Revision 15 (June 2015)	Updated "ProASIC3E Ordering Information". Interchanged the positions of Y-Security Feature and I- Application (Temperature Range) (SAR 67296). Added Note "Only devices with package size greater than or equal to 5x5 are supported". Updated Commercial and Industrial Junction Temperatures (SAR 67588).	1-III
	Added the A3PE3000 package to Table 2-5 (SARs 52320 and 58737).	2-5
	Updated "VCCIBx I/O Supply Voltage" (SAR 43323).	3-1
Revision 14 (May 2014)	Added 2 mA and 6 mA I/O short currents values in " <i>I/O Short Currents IOSH/IOSL</i> " (SAR 56295). Added 2 mA and 6 mA minimum and maximum DC input and output levels in " <i>Minimum and Maximum DC Input and Output Levels</i> "(SAR 56295). Added 3.3 V LVTTL / 3.3 V LVCMOS High Slew Commercial-Case Conditions for 2 mA and 6 mA in " <i>3.3 V LVTTL / 3.3 V LVCMOS High Slew</i> " (SAR 56295). Added 3.3 V LVTTL / 3.3 V LVCMOS Low Slew Commercial-Case Conditions for 2 mA and 6 mA in " <i>3.3 V LVTTL / 3.3 V LVCMOS Low Slew</i> " (SAR 56295).	2-22 2-24 2-25 2-25
Revision 13 (January 2013)	In the "Features and Benefits" section, updated the <i>Clock Conditioning Circuit (CCC)</i> and <i>PLL</i> Wide Input Frequency Range from '1.5 MHz to 200 MHz' to '1.5MHz to 350 MHz' based on Table 2-98 (SAR 22196).	1-I
	The "ProASIC3E Ordering Information" section has been updated to mention "Y" as "Blank" mentioning "Device Does Not Include License to Implement IP Based on the Cryptography Research, Inc. (CRI) Patent Portfolio" (SAR 43220).	1-III
	Added a note to " <i>Recommended Operating Conditions</i> <sup>1</sup> " table (SAR 42716): The programming temperature range supported is $T_{ambient} = 0^{\circ}\text{C}$ to $85^{\circ}\text{C}$ .	2-2
	The note in " <i>ProASIC3E CCC/PLL Specification</i> " table referring the reader to SmartGen was revised to refer instead to the online help associated with the core (SAR 42571).	2-70
	Libero Integrated Design Environment (IDE) was changed to Libero System-on-Chip (SoC) throughout the document (SAR 40285). Live at Power-Up (LAPU) has been replaced with 'Instant On'.	NA
Revision 12 (September 2012)	The "Security" section was modified to clarify that Microsemi does not support read-back of programmed data.	1-1

Revision	Changes	Page
v2.0 (continued)	Table 3-6 • Temperature and Voltage Derating Factors for Timing Delays was updated.	3-5
	Table 3-5 • Package Thermal Resistivities was updated.	3-5
	Table 3-10 • Different Components Contributing to the Dynamic Power Consumption in ProASIC3E Devices was updated.	3-8
	$t_{WRO}$ and $t_{CCKH}$ were added to Table 3-94 • RAM4K9 and Table 3-95 • RAM512X18.	3-74 to 3-74
	The note in Table 3-24 • I/O Input Rise Time, Fall Time, and Related I/O Reliability was updated.	3-23
	Figure 3-43 • Write Access After Write onto Same Address, Figure 3-44 • Read Access After Write onto Same Address, and Figure 3-45 • Write Access After Read onto Same Address are new.	3-71 to 3-73
	Figure 3-53 • Timing Diagram was updated.	3-80
	Notes were added to the package diagrams identifying if they were top or bottom view.	N/A
	The A3PE1500 "208-Pin PQFP" table is new.	4-4
	The A3PE1500 "484-Pin FBGA" table is new.	4-18
	The A3PE1500 "A3PE1500 Function" table is new.	4-24
Advance v0.6 (January 2007)	In the "Packaging Tables" table, the number of I/Os for the A3PE1500 was changed for the FG484 and FG676 packages.	ii
Advance v0.5 (April 2006)	B-LVDS and M-LDVS are new I/O standards added to the datasheet.	N/A
	The term flow-through was changed to pass-through.	N/A
	Figure 2-8 • Very-Long-Line Resources was updated.	2-8
	The footnotes in Figure 2-27 • CCC/PLL Macro were updated.	2-28
	The Delay Increments in the Programmable Delay Blocks specification in Figure 2-24 • ProASIC3E CCC Options.	2-24
	The "SRAM and FIFO" section was updated.	2-21
	The "RESET" section was updated.	2-25
	The "WCLK and RCLK" section was updated.	2-25
	The "RESET" section was updated.	2-25
	The "RESET" section was updated.	2-27
	B-LVDS and M-LDVS are new I/O standards added to the datasheet.	N/A
	The term flow-through was changed to pass-through.	N/A
	Figure 2-8 • Very-Long-Line Resources was updated.	2-8
	The footnotes in Figure 2-27 • CCC/PLL Macro were updated.	2-28
	The Delay Increments in the Programmable Delay Blocks specification in Figure 2-24 • ProASIC3E CCC Options.	2-24
	The "SRAM and FIFO" section was updated.	2-21
	The "RESET" section was updated.	2-25
	The "WCLK and RCLK" section was updated.	2-25

Revision	Changes	Page
Advance v0.5 (continued)	The "I/O User Input/Output" pin description was updated to include information on what happens when the pin is unused.	2-50
	The "JTAG Pins" section was updated to include information on what happens when the pin is unused.	2-51
	The "Programming" section was updated to include information concerning serialization.	2-53
	The "JTAG 1532" section was updated to include SAMPLE/PRELOAD information.	2-54
	The "DC and Switching Characteristics" chapter was updated with new information.	Starting on page 3-1
	Table 3-6 was updated.	3-5
	In Table 3-10, PAC4 was updated.	3-8
	Table 3-19 was updated.	3-20
	The note in Table 3-24 was updated.	3-23
	All Timing Characteristics tables were updated from LVTTL to Register Delays	3-26 to 3-64
Advance v0.4 (October 2005)	The Timing Characteristics for RAM4K9, RAM512X18, and FIFO were updated.	3-74 to 3-79
	F <sub>TCKMAX</sub> was updated in Table 3-98.	3-80
Advance v0.4 (October 2005)	The "Packaging Tables" table was updated.	ii
Advance v0.3	Figure 2-11 was updated.	2-9
	The "Clock Resources (VersaNets)" section was updated.	2-9
	The "VersaNet Global Networks and Spine Access" section was updated.	2-9
	The "PLL Macro" section was updated.	2-15
	Figure 2-27 was updated.	2-28
	Figure 2-20 was updated.	2-19
	Table 2-5 was updated.	2-25
	Table 2-6 was updated.	2-25
	The "FIFO Flag Usage Considerations" section was updated.	2-27
	Table 2-33 was updated.	2-51
	Figure 2-24 was updated.	2-31
	The "Cold-Sparing Support" section is new.	2-34
	Table 2-45 was updated.	2-64
	Table 2-48 was updated.	2-81
	Pin descriptions in the "JTAG Pins" section were updated.	2-51
	The "Pin Descriptions" section was updated.	2-50
	Table 3-7 was updated.	3-6